

Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) An electro-optical device, comprising:

an active matrix substrate having on the same plane a plurality of scanning lines, a plurality of signal lines provided to intersect the scanning lines, a plurality of pixel electrodes provided at the intersection portions of the scanning lines and the signal lines, and a peripheral driving circuit to matrix drive the pixel electrodes;

a counter substrate having comprising:

~~a common electrode on one surface and facing the active matrix substrate such that the common electrode is opposite to the pixel electrodes; electrodes of the active matrix, and~~

~~a light shielding film;~~

~~a seal that forms a sealed region between the active matrix substrate and the counter substrate, the peripheral driving circuit being disposed at least partially within the sealed region; and~~

~~a liquid crystal layer interposed disposed in the sealed region between the active matrix substrate and the counter-substrate; substrate,~~

~~wherein a portion, where the common electrode and the light shielding film are in a non-overlapping arrangement overlaps with at least one of the peripheral driving circuit or with and wiring lines to supply for supplying signals to the peripheral driving circuit in plan-view, being removed view.~~

2. (Currently Amended) An electro-optical device, comprising:

an active matrix substrate having on the same plane a plurality of scanning lines, a plurality of signal lines provided to intersect the scanning lines, a plurality of pixel

electrodes provided at the intersection portions of the scanning lines and the signal lines, and a peripheral driving circuit to matrix drive the pixel electrodes;

a counter-substrate, comprising: one surface thereof being provided with
_____ a common electrode over the covering an entire surface thereof, of the
counter substrate, the common electrode facing the active matrix substrate such that the
common electrode is opposite to the pixel electrodes; electrodes of the active matrix, and

_____ a light shielding film;

_____ a seal that forms a sealed region between the active matrix substrate and the
counter substrate, the peripheral driving circuit being disposed at least partially within the
sealed region; and

_____ a liquid crystal layer interposed disposed in the sealed portion between the
active matrix substrate and the counter-substrate; substrate,

_____ wherein the counter substrate and the light shielding film are in a non-
overlapping arrangement being provided so as to not overlap with at least one of the
peripheral driving circuit or with and wiring lines to supply for supplying signals to the
peripheral driving circuit in plan view.

3. (Currently Amended) The electro-optical device according to claim 1,
wherein the peripheral driving circuit being comprises equipped with thin film transistors
having channel regions made of single crystal silicon.

4. (Currently Amended) The electro-optical device according to claim 1,
wherein the a frequency of at least one of driving the signals inputted into supplied to the
peripheral driving circuit being is equal to or more than 10 MHz.

5. (Currently Amended) The electro-optical device according to claim 1,
wherein the peripheral driving circuit including comprises at least one of a data line driving

circuit and a sample hold circuit, and the wiring lines including comprise at least one of clock signal lines, image signal selecting lines, and image signal lines.

6. (Currently Amended) A method of manufacturing an electro-optical device, comprising:

forming a plurality of pixel electrodes and a peripheral driving circuit to matrix drive the plurality of pixel electrodes on one surface of an active matrix substrate;

forming a common electrode and a light shielding film on one surface of a counter substrate over the an entire surface thereof; of a counter substrate;

removing a portion where arranging the common electrode and the light shielding film of the counter substrate overlaps in a non-overlapping arrangement with at least one of the peripheral driving circuit or with and wiring lines for supplying signals to the peripheral driving circuit in plan view;

bonding the active matrix substrate to the counter substrate with a predetermined gap therebetween between the active matrix substrate and the counter substrate using a sealing material to form a sealed region, such that the peripheral driving circuit being disposed partially within the sealed region, and the common electrode is opposite to facing the pixel electrodes; electrodes of the active matrix; and

forming a liquid crystal layer by injecting liquid crystal into a space the sealed region formed by the active matrix substrate, the counter substrate, and the sealing material.

7. (Original) An electronic apparatus, comprising:

the electro-optical device according to claim 1.